NSN 5961-01-019-6288

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-019-6288 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** 0.762 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 15.00 milliamperes source cutoff current and 500.00 microamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 160.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0